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Devices

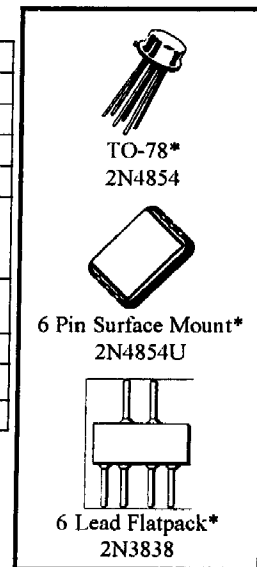
2N3838

2N4854
2N4854U

MAXIMUM RATINGS

| Ratings | Sym | 2N3838 ⁽²⁾ | | 2N4854, U | | Unit |
|--|------------------|-----------------------|--------------|---------------------|--------------|------|
| Collector-Emitter Voltage | V _{CEO} | 40 | | 40 | | Vdc |
| Collector-Base Voltage | V _{CBO} | 60 | | 60 | | Vdc |
| Emitter-Base Voltage | V _{EBO} | 5.0 | | 5.0 | | Vdc |
| Collector Current | I _C | 600 | | 600 | | mAdc |
| | | One Trans | Total Device | One Trans | Total Device | |
| Total Power Dissipation @ T _A = +25°C | P _T | 0.25 ⁽³⁾ | 0.35 | 0.30 ⁽³⁾ | 0.60 | W |
| @ T _C = +25°C ⁽¹⁾ | | 0.7 ⁽⁴⁾ | 1.4 | 1.0 ⁽³⁾ | 2.0 | W |
| Operating & Storage Junction Temp. Range | T _J | 200 | | | | °C |
| Operating & Storage Junction Temp. Range | T _{stg} | -55 to +200 | | | | °C |
| Lead to Case Voltage | | ±120 | | | | Vdc |

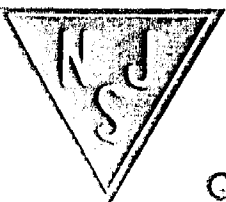
- 1) T_C rating do not apply to Surface Mount devices (2N4854U)
- 2) For T_A > +25°C Derate linearly 1.43 mW/°C (one transistor) 2.00 mW/°C (both transistors)
- 3) For T_A > +25°C Derate linearly 1.71 mW/°C (one transistor) 3.43 mW/°C (both transistors)
- 4) For T_C > +25°C Derate linearly 4.0 mW/°C (one transistor) 8.0 mW/°C (both transistors)
- 5) For T_C > +25°C Derate linearly 5.71 mW/°C (one transistor) 11.43 mW/°C (both transistors)



*See MILPRF19500/421 for package dimensions.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristics | Symbol | Min. | Max. | Unit |
|---|----------------------|------|----------|--------------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Breakdown Current I _C = 10 mAdc | V _{(BR)CEO} | 40 | | Dc |
| Collector-Base Cutoff Current V _{CB} = 60 Vdc | I _{CBO(1)} | | 10 | μAdc |
| Collector-Base Cutoff Current V _{CB} = 50 Vdc | I _{CBO(2)} | | 50 10 | ηAdc |
| Emitter-Base Cutoff Current V _{EB} = 5.0 Vdc V _{EB} = 3.0 Vdc | I _{EBO} | | 10 10 | μAdc ηAdc |



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

ELECTRICAL CHARACTERISTICS (con't)

| Characteristics | Symbol | Min. | Max. | Unit |
|--|--------------------|-----------------------------------|------|-----------------|
| ON CHARACTERISTICS | | | | |
| Forward-Current Transfer Ratio $I_C = 150 \text{ mAdc}, V_{CE} = 1 \text{ Vdc}$ $I_C = 100 \text{ } \mu\text{Adc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ $I_C = 300 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ | h_{FE} | 50 35 50 75 100 35 | 300 | |
| Collector-Emitter Saturation Voltage $I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$ | $V_{CE(sat)}$ | | 0.40 | Vdc |
| Base-Emitter Saturation Voltage $I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$ | $V_{BE(sat)}$ | 0.80 | 1.25 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | |
| Forward Current Transfer Ratio $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ | h_{fe} | 60 | 300 | |
| Forward Current Transfer Ratio, Magnitude $I_C = 20 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz}$ | $ h_{fe} $ | 2.0 | 10 | |
| Small-Signal Common Emitter Input Impedance $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ | h_{je} | 1.5 | 9.0 | $k\Omega$ |
| Small-Signal Common Emitter Output Admittance $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ | h_{oe} | | 50 | μhmo |
| Output Capacitance $V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$ | C_{obo} | | 8.0 | pF |
| Noise Figure $I_C = 100 \text{ } \mu\text{Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, R_G = 1.0 \text{ k}\Omega$ | NF | | 8.0 | dB |
| SWITCHING CHARACTERISTICS | | | | |
| Turn-On Time (See Figure 4 of MIL-PRF-19500/421) | t_{on} | | 45 | ηs |
| Turn-Off Time (See Figure 5 of MIL-PRF-19500/421) | t_{off} | | 300 | ηs |
| Pulse Response (See Figure 6 of MIL-PRF-19500/421) | $t_{on} + t_{off}$ | | 18 | ηs |
| Collector-Emitter Non-Latching Voltage (See Figure 7 of MIL-PRF-19500/421) | V_{CEO} | 40 | | Vdc |